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July 1999 Revised December 2013

## 74VCX86

# Low Voltage Quad 2-Input Exclusive-OR Gate with 3.6V Tolerant Inputs and Outputs

## **General Description**

The VCX86 contains four 2-input exclusive OR gates. This product is designed for low voltage (1.2V to 3.6V)  $V_{CC}$  applications with I/O compatibility up to 3.6V

The 74VCX86 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

### **Features**

- 1.2V to 3.6V V<sub>CC</sub> supply operation
- 3.6V tolerant inputs and outputs
- t<sub>P</sub>

3.0 ns max for 3.0V to 3.6V  $V_{CC}$ 

- Power-off high impedance inputs and outputs
- Static Drive (I<sub>OH</sub>/I<sub>OL</sub>) ±24 mA @ 3.0V V<sub>CC</sub>
- Uses proprietary noise/EMI reduction circuitr
- Latchup performance exceeds JEDEC 78 conditions
- ESD performance:

Human body model > 2000V Machine model > 250V

■ Leadless Pb-Free DQFN package

## **Ordering Code:**

Order Number	Package Description	
74VCX86M M14A		14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VCX86BQX MLP014A (Note 1) 74VCX86MTC MTC14		Pb-Free 14-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MO-241, 2.5 x 3.0mm
		14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

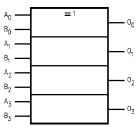
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Pb-Free package per JEDEC J-STD-020B.

Note 1: DQFN package available in Tape and Reel only.

# Logic Symbol

IEEE/IEC



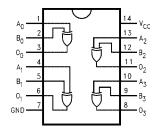
# Pin Descriptions

Pin Names	Description
A <sub>n</sub> , B <sub>n</sub>	Inputs
O <sub>n</sub>	Outputs
DAP	No Connect

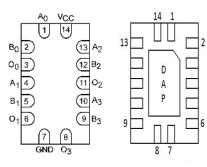
Note: DAP (Die Attach Pad)

# **Connection Diagrams**

Pin Assignments for SOIC and TSSOP



Pad Assignments for DQFN



(Top View)

(Bottom View)

## **Absolute Maximum Ratings**(Note 2)

-0.5V to +4.6V Supply Voltage (V<sub>CC</sub>) DC Input Voltage (V<sub>I</sub>) -0.5V to +4.6V Output Voltage (V<sub>O</sub>) HIGH or LOW State (Note 3) -0.5V to  $V_{CC} + 0.5V$  $V_{CC} = 0V$ -0.5V to +4.6VDC Input Diode Current ( $I_{IK}$ )  $V_I < 0V$ -50 mA DC Output Diode Current (I<sub>OK</sub>)  $V_O < 0 \\ V$ -50 mA +50 mA  $V_O > V_{CC}$ DC Output Source/Sink Current  $(I_{OH}/I_{OL})$  $\pm 50 \ mA$ DC V<sub>CC</sub> or GND Current per Supply Pin (I<sub>CC</sub> or Ground) ±100 mA

# Recommended Operating Conditions (Note 4)

Power Supply 1.2V to 3.6V Operating Input Voltage -0.3V to +3.6VOutput Voltage (V<sub>O</sub>) HIGH or LOW State 0V to  $V_{CC}$ Output Current in I<sub>OH</sub>/I<sub>OL</sub>  $V_{CC} = 3.0V \text{ to } 3.6V$ ±24 mA  $V_{CC} = 2.3V \text{ to } 2.7V$  $\pm 18~mA$  $V_{CC} = 1.65V \text{ to } 2.3V$  $\pm 6~\text{mA}$  $V_{CC} = 1.4V \text{ to } 1.6V$ ±2 mA ±100 μA  $V_{CC} = 1.2V$ Free Air Operating Temperature (T<sub>A</sub>) -40°C to +85°C Minimum Input Edge Rate ( $\Delta t/\Delta V$ )

 $V_{IN}=0.8V\ to\ 2.0V,\ V_{CC}=3.0V$  10 ns/V Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be

the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: IO Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

#### **DC Electrical Characteristics**

Storage Temperature Range  $(T_{STG})$ 

Symbol	Parameter	Conditions	(V)	Min	Max	Units
V <sub>IH</sub>	HIGH Level Input Voltage		2.7 - 3.6	2.0		
			2.3 - 2.7	1.6		
			1.65 - 2.3	0.65 × V <sub>CC</sub>		V
			1.4 - 1.6	0.65 × V <sub>CC</sub>		
			1.2	0.65 × V <sub>CC</sub>		
V <sub>IL</sub>	LOW Level Input Voltage		2.7 - 3.6		0.8	
			2.3 - 2.7		0.7	
			1.65 - 2.3		$0.35 \times V_{CC}$	V
			1.4 - 1.6		$0.35 \times V_{CC}$	
			1.2			
V <sub>OH</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = -100 μA	2.7 - 3.6	V <sub>CC</sub> - 0.2		
		I <sub>OH</sub> = -12 mA	2.7	2.2		
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
		$I_{OH} = -100 \mu A$	2.3 - 2.7	V <sub>CC</sub> - 0.2		
		$I_{OH} = -6 \text{ mA}$	2.3	2.0		
		$I_{OH} = -12 \text{ mA}$	2.3	1.8		V
		$I_{OH} = -18 \text{ mA}$	2.3	1.7		
		$I_{OH} = -100 \mu A$	1.65 - 2.3	V <sub>CC</sub> - 0.2		
		$I_{OH} = -6 \text{ mA}$	1.65	1.25		
		$I_{OH} = -100 \mu A$	1.4 - 1.6	V <sub>CC</sub> - 0.2		
		$I_{OH} = -2 \text{ mA}$	1.4	1.05		
		I <sub>OH</sub> = -100 μA	1.2	V <sub>CC</sub> - 0.2		

-65°C to +150°C

# DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	v <sub>cc</sub>	Min	Max	Units
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.7 - 3.6		0.2	
		I <sub>OL</sub> = 12 mA	2.7		0.4	
		I <sub>OL</sub> = 18 mA	3.0		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.55	
		$I_{OL} = 100 \mu A$	2.3 - 2.7		0.2	
		I <sub>OL</sub> = 12 mA	2.3		0.4	V
		I <sub>OL</sub> = 18 mA	2.3		0.6	V
		$I_{OL} = 100 \mu A$	1.65 - 2.3		0.2	
		I <sub>OL</sub> = 6 mA	1.65		0.3	
		$I_{OL} = 100 \mu A$	1.4 - 1.6		0.2	
		I <sub>OL</sub> = 2 mA	1.4		0.35	
		$I_{OL} = 100 \mu A$	1.2		0.05	
II	Input Leakage Current	$0 \le V_I \le 3.6V$	1.2 - 3.6		±5.0	μА
I <sub>OFF</sub>	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μА
Icc	Quiescent Supply Current	V <sub>I</sub> = V <sub>CC</sub> or GND	1.2 - 3.6		20	μΑ
		$V_{CC} \leq (V_I)$	1.2 - 3.6		±20	μΑ
Δl <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	V <sub>IH</sub> = V <sub>CC</sub> -0.6V	2.7 - 3.6		750	μА

# AC Electrical Characteristics (Note 5)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> = -40°0	C to +85°C	Units	Figure
Cymbol			(V)	Min	Max		Number
t <sub>PHL</sub>	Propagation Delay	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$3.3 \pm 0.3$	0.6	3.0		_
t <sub>PLH</sub>			$2.5 \pm 0.2$	0.8	3.9		Figures 1, 2
			$1.8\pm0.15$	1.0	7.8	ns	., _
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	$1.5\pm0.1$	1.0	15.6		Figures
			1.2	1.5	39		3, 4
toshl	Output to Output Skew	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$3.3 \pm 0.3$		0.5		
toslh	(Note 6)		$2.5 \pm 0.2$		0.5		
			$1.8\pm0.15$		0.75	ns	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	$1.5\pm0.1$		1.5		
			1.2		1.5		

Note 5: For  $C_L = 50_P F$ , add approximately 300 ps to the AC maximum specification.

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>).

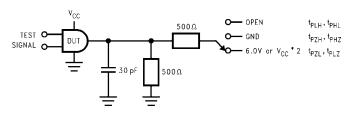
# **Dynamic Switching Characteristics**

Symbol	Parameter	Conditions	V <sub>CC</sub>	$T_A = +25^{\circ}C$	Units	
Cymbol	T drameter	Conditions	(V)	Typical	Jinto	
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.25		
			2.5	0.6	V	
			3.3	8.0		
V <sub>OLV</sub>	Quiet Output Dynamic Valley V <sub>OL</sub>	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.25		
			2.5	-0.6	V	
			3.3	-0.8		
V <sub>OHV</sub>	Quiet Output Dynamic Valley V <sub>OH</sub>	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.5		
			2.5	1.9	V	
			3.3	2.2		

# Capacitance

Symbol	Parameter	Conditions	$T_A = +25^{\circ}C$	Units
Cymbol	i didilicioi	Conditions	Typical	
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 1.8, 2.5 \text{V or } 3.3 \text{V, } V_{I} = 0 \text{V or } V_{CC}$	6	pF
C <sub>OUT</sub>	Output Capacitance	$V_{I} = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	7	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_I = 0V \text{ or } V_{CC}, f = 10 \text{ MHz}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	20	pF

# AC Loading and Waveforms (V $_{CC}$ 3.3V $\pm$ 0.3V to 1.8V $\pm$ 0.15V)



TEST	SWITCH		
t <sub>PLH</sub> , t <sub>PHL</sub>	Open		
	FIGURE 4. AC Took Circuit		

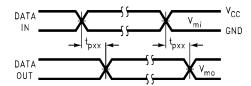
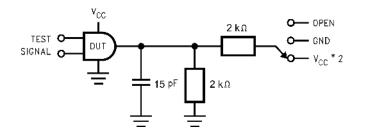


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

Symbol	v <sub>cc</sub>				
Cymbol	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V		
V <sub>mi</sub>	1.5V	V <sub>CC</sub> /2	V <sub>CC</sub> /2		
V <sub>mo</sub>	1.5V	V <sub>CC</sub> /2	V <sub>CC</sub> /2		

# AC Loading and Waveforms (V<sub>CC</sub> 1.5V $\pm$ 0.1V to 1.2V)



TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
$t_{PZL}, t_{PLZ}$	$V_{CC}$ x 2 at $V_{CC}$ = 1.5 ± 0.1V
$t_{PZH},t_{PHZ}$	GND

FIGURE 3. AC Test Circuit

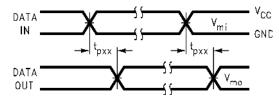


FIGURE 4. Waveform for Inverting and Non-Inverting Functions

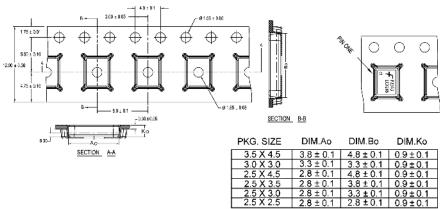
Symbol	v <sub>cc</sub>
	1.5V ± 0.1V
V <sub>mi</sub>	V <sub>CC</sub> /2
V <sub>mo</sub>	V <sub>CC</sub> /2

## **Tape and Reel Specification**

Tape Format for DQFN

Tape I office to the III						
Package		Таре	Number	Cavity	Cover Tape	
	Designator	Section	Cavities	Status	Status	
		Leader (Start End)	125 (typ)	Empty	Sealed	
	BQX	Carrier	2500/3000	Filled	Sealed	
		Trailer (Hub End)	75 (typ)	Empty	Sealed	

#### TAPE DIMENSIONS inches (millimeters)



DIMENSIONS ARE IN MILLIMETERS

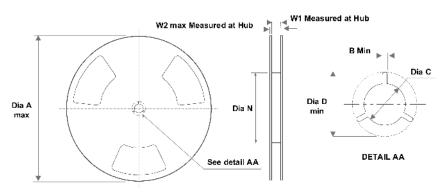
#### NOTES: unless otherwise specified

- 1. Cummulative pitch for feeding holes and cavities (chip pockets) not to exceed 0.008[0.20] over 10 pitch span.
- Smallest allowable bending radius.
   Thru hole inside cavity is centered within cavity.
- 4. Tolerance is ±0.002[0.05] for these dimensions on all 12mm tapes.

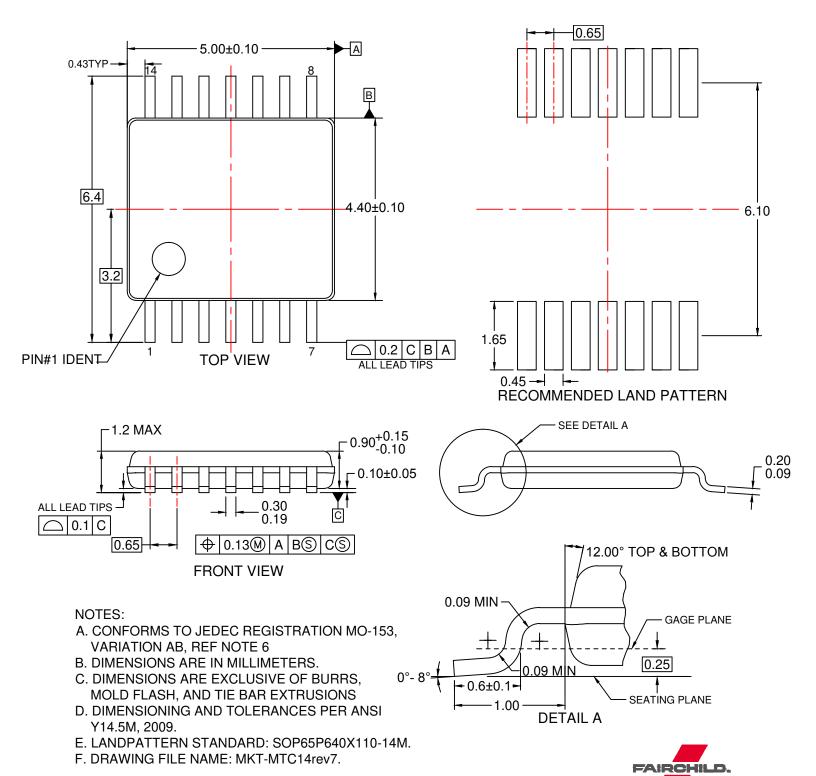
  5. Ao and Bo measured on a plane 0.120[0.30] above the bottom of the pocket.

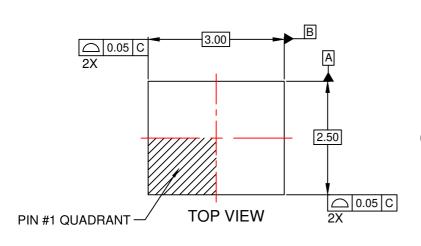
  6. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- Pocket position relative to sprocket hole measured as true position of pocket. Not pocket hole.
   Controlling dimension is millimeter. Diemension in inches rounded.

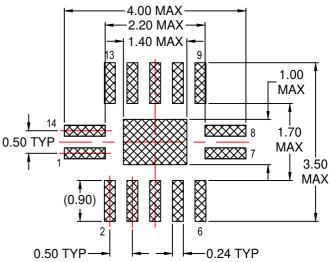
#### **REEL DIMENSIONS** inches (millimeters)

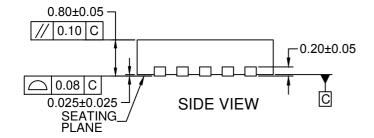


Tape Size	Α	В	С	D	N	W1	W2
12 mm	13.0	0.059	0.512	0.795	7.008	0.488	0.724
	(330)	(1.50)	(13.00)	(20.20)	(178)	(12.4)	(18.4)

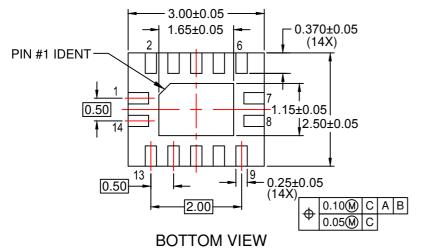












#### NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-241, VARIATION AA
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
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